

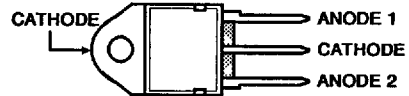
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May 1991

15A Ultrafast Dual Diode
 With Soft Recovery Characteristic

HARRIS SEMICONDUCTOR SECTOR **T-23-07**
 Package

TO-218AC
 TOP VIEW



Features

- Ultrafast with Soft Recovery Characteristic ($t_{rr} < 30ns$)
- +175°C Rated Junction Temperature
- Reverse Voltage Up to 200V
- Avalanche Energy Rated

Applications

- Switching Power Supply
- Power Switching Circuits
- General Purpose

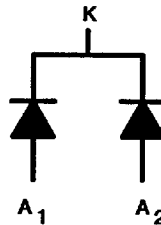
Description

MUR3010PT, MUR3010PT, MUR3020PT and RURD1510, RURD1515, RURD1520 are ultrafast dual diodes ($t_{rr} < 30ns$) with soft recovery characteristics ($t_a/t_b \approx 1$). They have a low forward voltage drop and are of planar, silicon nitride passivated, ion-implanted, epitaxial construction.

These devices are intended for use as energy steering/clamping diodes and rectifiers in a variety of switching power supplies and other power switching applications. Their low stored charge and ultrafast recovery with soft recovery characteristics minimizes ringing and electrical noise in many power switching circuits thus reducing power loss in the switching transistor.

All are supplied in TO-218AC packages.

Symbol



Absolute Maximum Ratings ($T_C = +25^\circ C$)

	MUR3010PT RURD1510	MUR3010PT RURD1515	MUR3020PT RURD1520
Peak Repetitive Reverse Voltage..... V_{RRM}	100V	150V	200V
Working Peak Reverse Voltage..... V_{RWM}	100V	150V	200V
DC Blocking Voltage..... V_R	100V	150V	200V
Average Rectified Forward Current..... $I_F(AV)$ (Total device forward current at rated V_F and $T_C = 150^\circ C$)	15A	15A	15A
Peak Forward Repetitive Current..... I_{FRM} (Rated V_F , square wave 20kHz)	30A	30A	30A
Nonrepetitive Peak Surge Current..... I_{FSM} (Surge applied at rated load condition halfwave 1phase 60Hz)	200A	200A	200A
Operating and Storage Temperature..... T_{STG}, T_J	-55°C to +175°C	-55°C to +175°C	-55°C to +175°C

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 ULTRA-FAST
 RECTIFIERS

T-23-07

SYMBOL	TEST CONDITION	LIMITS									UNITS
		MUR3010PT, RURD1510			MUR3015PT, RURD1515			MUR3020PT, RURD1520			
		MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
V _F	I _F = 15A T _C = +150°C	-	-	0.85	-	-	0.85	-	-	0.85	V
	I _F = 15A T _C = +25°C	-	-	1.05	-	-	1.05	-	-	1.05	V
I _R @ T _C = +150°C	V _R = 100V	-	-	500	-	-	-	-	-	-	μA
	V _R = 150V	-	-	-	-	-	500	-	-	-	μA
	V _R = 200V	-	-	-	-	-	-	-	-	500	μA
I _R @ T _C = +25°C	V _R = 100V	-	-	10	-	-	-	-	-	-	μA
	V _R = 150V	-	-	-	-	-	10	-	-	-	μA
	V _R = 200V	-	-	-	-	-	-	-	-	10	μA
t _{rr}	I _F = 1A	-	-	30	-	-	30	-	-	30	ns
	I _F = 15A	-	-	35	-	-	35	-	-	35	ns
t _a	I _F = 1A	-	18	-	-	18	-	-	18	-	ns
	I _F = 15A	-	20	-	-	20	-	-	20	-	ns
t _b	I _F = 1A	-	9	-	-	9	-	-	9	-	ns
	I _F = 15A	-	10	-	-	10	-	-	10	-	ns
R _{θjc}		-	-	1.5	-	-	1.5	-	-	1.5	°C/W
W _{avl}	see Fig. 7&8	-	-	20	-	-	20	-	-	20	mj

Definitions

V_F = Instantaneous forward voltage (pw = 300μs, D = 2%).

I_R = Instantaneous reverse current (pw = 300μs, D = 2%).

t_{rr} = Reverse recovery time at di_F/dt = 100A/μs (See Figure 2), summation of t_a + t_b.

t_a = Time to reach peak reverse current at di_F/dt = 100A/μs (See Figure 2).

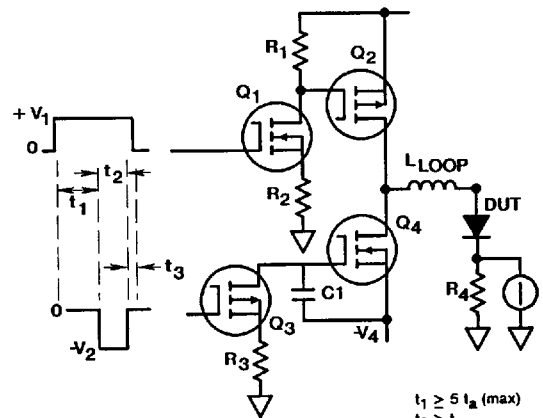
t_b = Time from peak I_{RM} to projected zero crossing of I_{RM} based on a straight line from peak I_{RM} through 25% of I_{RM}. (See Figure 2)

R_{θjc} = Thermal resistance junction to case.

W_{avl} = Controlled avalanche energy (See Figures 7 & 8).

pw = pulse width.

D = duty cycle.



V₁ amplitude controls I_F
 V₂ amplitude controls di/dt
 L₁ = self inductance of R₄

$$t_1 \geq 5 t_a (\text{max})$$

$$t_2 > t_{rr}$$

$$t_3 > 0$$

$$\frac{L_1}{R_4} \leq \frac{t_a (\text{min})}{10}$$

FIGURE 1. t_{rr} TEST CIRCUIT

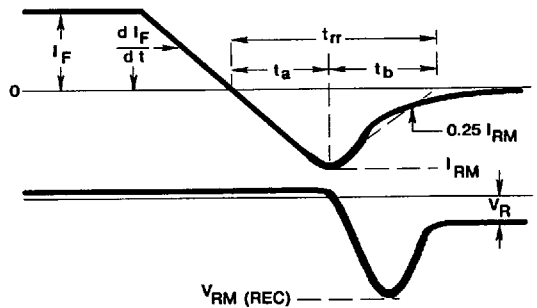


FIGURE 2. DEFINITIONS OF t_{rr}, t_a AND t_b

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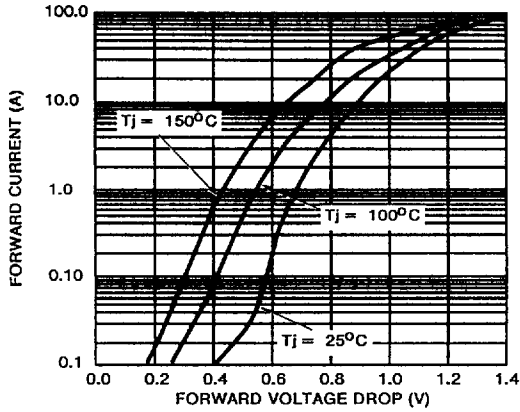


FIGURE 3. FORWARD VOLTAGE vs FORWARD CURRENT CHARACTERISTIC

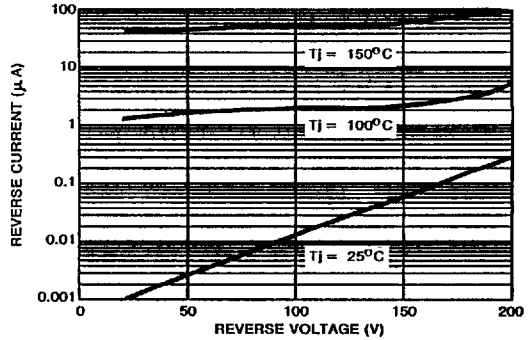


FIGURE 4. REVERSE VOLTAGE vs REVERSE CURRENT CHARACTERISTIC

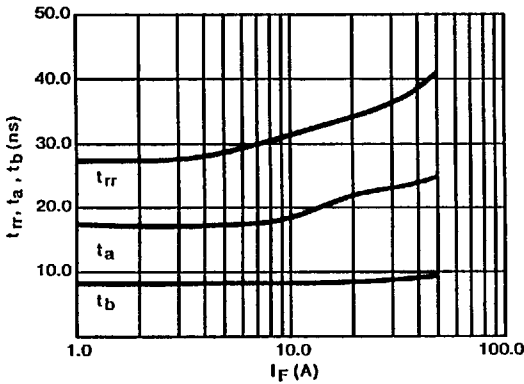


FIGURE 5. TYPICAL t_{rr} , t_a , t_b vs FORWARD CURRENT

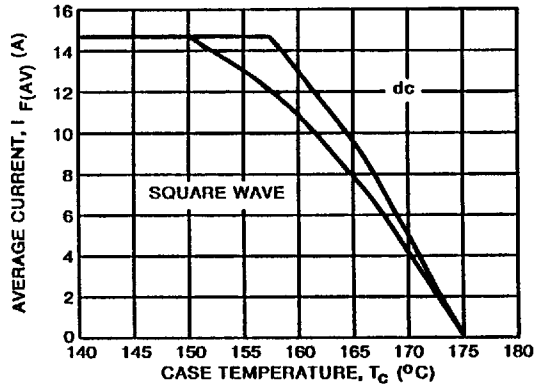


FIGURE 6. TYPICAL CURRENT DERATING CURVE w.r.t. CASE TEMPERATURE

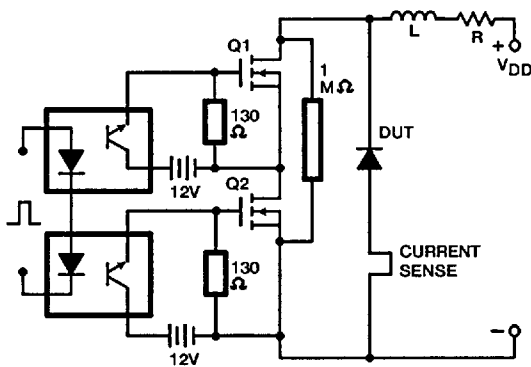


FIGURE 7. AVALANCHE ENERGY TEST CIRCUIT

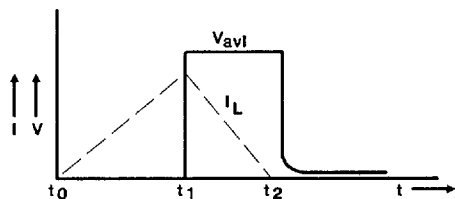


FIGURE 8. CURRENT VOLTAGE WAVEFORM

$$I_{L\text{peak}} = 1A, L = 40mH, R < 0.1\Omega, W_{\text{avt}} = (1/2) L I_L^2 [V_{\text{avt}} / (V_{\text{avt}} - V_{\text{dd}})]$$